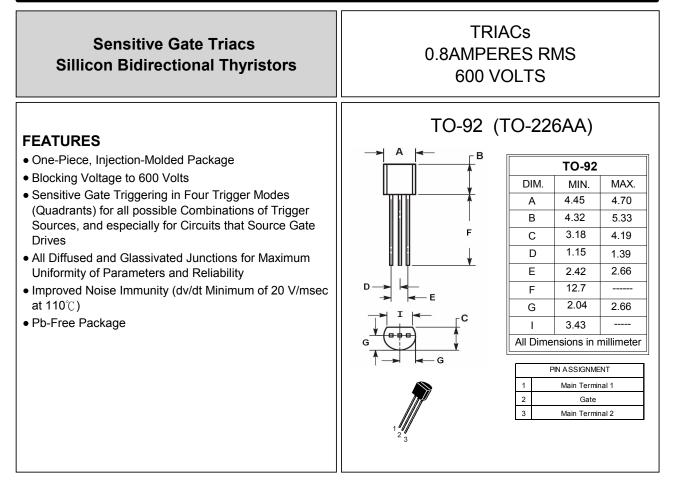
LITE ON SEMICONDUCTOR

97A8



MAXIMUM RATINGS (Tj= 25°C unless otherwise noticed)

Rating	Symbol	Value	Unit	
Peak Repetitive Off– State Voltage (TJ= -40 to 125°), Sine Wave, 50 to 60 Hz; Gate Open)	Vdrm, Vrrm	600	Volts	
On-State RMS Current Full Cycle Sine Wave 50 to 60 Hz (Tc = 50℃)	IT(RMS)	0.8	Amp	
Peak Non-Repetitive Surge Current Full Cycle Sine Wave 60 Hz (Tj =25℃)	Ітѕм	9.0	Amps	
Circuit Fusing Consideration (t = 8.3 ms)	l ² t	0.34	A ² s	
Peak Gate Power ($t\leq$ 2.0us ,Tc = 80 $^\circ\!\!{\rm C}$)	Рдм	5.0	Watt	
Average Gate Power (Tc = 80 $^\circ\!{\rm C}$, $t \leq$ 8.3 ms)	PG(AV)	0.1	Watt	
Peak Gate Current ($t \leq$ 2.0us ,Tc = 80 $^\circ\!\!\mathbb{C}$)	lgм	1.0	Amp	
Peak Gate Voltage ($t \leq$ 2.0us ,Tc = 80 $^\circ\!\!\mathbb{C}$)	Vgм	5.0	Volts	
Operating Junction Temperature Range	TJ	-40 to +110	°C	
Storage Temperature Range	Tstg	-40 to +150	°C	
Notice: (1) VDRM and VRRM for all types can be applied on a continuous basis. Blocking	REV	REV. 2, Oct-2010, KTXD23		

voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance - Junction to Lead - Junction to Case - Junction to Ambient	RthJL RthJC RthJA	60 75 150	°C /W
Maximum Lead Temperature for Soldering Purposes 1/8 from Case for 10 Seconds	TL	260	°C

ELECTRICAL CHARACTERISTICS (Tc=25°C unless otherwise noted)

Characteristics	Symbol	Min	Тур	Мах	Unit
OFF CHARACTERISTICS					
Peak Reptitive Forward or Reverse Blocking CurrentTj =25°C(VD=Rated VDRM and VRRM; Gate OPen)Tj =110°C	Idrm Irrm			10 100	uA uA
ON CHARACTERISTICS		•			
Peak Forward On-State Voltage (ITM=± 1A Peak @Tp \leq 2.0 ms, Duty Cycle \leq 2%)	Vтм			1.9	Volts
Gate Trigger Current (V _D = 12 Vdc; R _L = 100 Ohms)	IGT1 IGT2 IGT3 IGT4			5.0 5.0 5.0 7.0	mA
Holding Current (VD = 12 V, Initiating Current = \pm 200 mA, Gate Open)	lн		1.5	10	mA
Turn-On Time (VD = Rated VDRM , ITM = 1.0 A pk, IG = 25 mA)	tgt		2		us
Gate Trigger Voltage (V _D = 12 Vdc; RL =100 Ohms)	VGT1 VGT2 VGT3 VGT4	 	0.66 0.77 0.84 0.88	2.0 2.0 2.0 2.5	Volts
Latching Current (VD=12V,IG= 10 mA)	IL1 IL2 IL3 IL4	 	1.6 10.5 1.5 2.5	15 20 15 15	mA
Gate Non-Trigger Voltage (VD= 12V, RL= 100 Ohms , TJ=110 $^\circ\!\mathbb{C}$)	Vgd	0.1			Volts

DYNAMIC CHARACTERISTICS

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1.2 0.8 IT(RMS), RMS ON-STATE CURRENT(AMPS) IT(RMS), RMS ON-STATE CURRENT(AMPS) 0.7 1.0 0.6 0.8 0.5 0.4 0.6 0.3 0.4 0.2 0.2 0.1 0.0 0.0 0 100 125 0 100 125 25 50 75 25 50 75 Ta, AMBIENT TEMPERATURE(°C) Tc, CASE TEMPERATURE(℃) Figure 1. RMS Current Deratiing Versus Figure 2. RMS Current Deratiing Versus Ambient Temperature **Case Temperature** 1.2 10 1.0 P(AV), POWER PISSIPATION (WATTS) 0.8 tpy. ITM, INSTANTANEOUS ON-STATE CURRENT (AMP) 1 max. 0.6 1 0.4 0.2 1 . 0.0 0.1 1.0 0.0 0.1 0.2 0.3 0.4 0.5 0.6 0.7 0.8 0.9 IT(RMS), RMS ON-STATE CURRENT (AMPS) I Figure 3. Power Dissipation 1 1 0.01 0.4 0.8 1.2 2.0 2.4 2.8 1.6 VTM, INSTANTANEOUS ON-STATE VOLTAGE (VOLTS) Figure 4. On-State Characteristics

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16 1 R(t), TRANSENT THERMAL RESISTANCE (NORMALIZED) ITSM, PEAK SURGE CURRENT (AMPS) 12 8 0.1 CYCLE 4 TJ=25℃ f= 60MHz 0 0.01 10 1.00E-1 1.00E+0 1.00E+1 1.00E+2 1.00E+3 1.00E+4 1 100 NUMBER OF CYCLES t, TIME (ms) Figure 5. Transient Thermal Response Figure 6. Maximum Allowable Surge Current 100.0 1.2 Q4 1.1 ITSM, PEAK SURGE CURRENT (AMPS) ITSM, PEAK SURGE CURRENT (AMPS) Q3 1.0 Q2 Q4 10.0 0.9 Q3 Q1 Q2 0.8 0.7 Q 1.0 0.6 0.5 0.4 0.1 0.3 -50 -25 50 75 100 125 -25 0 25 50 75 0 25 -50 100 125 Tj, JUNCTION TEMPERATURE (℃) Tj, JUNCTION TEMPERATURE (°C) Figure 7. Typical Gate Trigger Current Versus Figure 8. Typical Gate Trigger Voltage Versus Junction Temperature Junction Temperature 10 100 IL, LATCHING CURRENT (mA) IH, HOLDING CURRENT (mA) Q2 10 MT2 Negative 1 Q4 Q3 MT2 Positive 1 Q1 0.1 0.1 -50 -25 0 25 50 75 100 125 -50 -25 0 25 50 75 100 125 Tj, JUNCTION TEMPERATURE (℃) Tj, JUNCTION TEMPERATURE (℃) Figure 9. Typical Latching Current Versus Figure 10. Typical Holding Current Versus

Junction Temperature

Junction Temperature

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